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## P-Channel 30-V (D-S) MOSFETs

## PRODUCT SUMMARY

Part Number	$V_{(BR)DSS}$ Min (V)	$r_{DS(on)}$ Max ( $\Omega$ )	$V_{GS(th)}$ (V)	$I_D$ (A)
VP0300L	-30	2.5 @ $V_{GS} = -12$ V	-2 to -4.5	-0.32
VP0300LS		2.5 @ $V_{GS} = -12$ V	-2 to -4.5	-0.5
VQ2001J		2 @ $V_{GS} = -12$ V	-2 to -4.5	-0.6
VQ2001P		2 @ $V_{GS} = -12$ V	-2 to -4.5	-0.6

## FEATURES

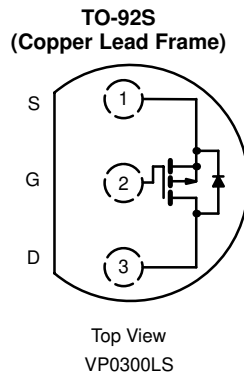
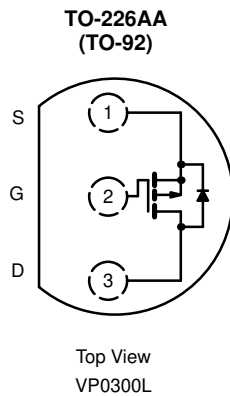
- High-Side Switching
- Low On-Resistance: 1.5  $\Omega$
- Moderate Threshold: -3.1 V
- Fast Switching Speed: 17 ns
- Low Input Capacitance: 60 pF

## BENEFITS

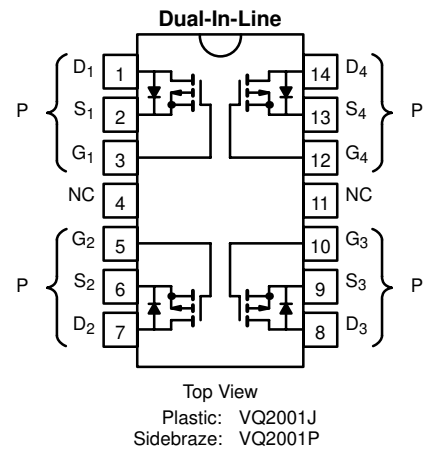
- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Switching
- Easily Driven Without Buffer

## APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems
- Power Supply, Converter Circuits
- Motor Control



For device marking, see the last page of this data sheet.

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)

Parameter	Symbol	VP0300L	VP0300LS	VQ2001J/P		Unit
				Single	Total Quad	
Drain-Source Voltage	$V_{DS}$	-30	-30	-30	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	$\pm 20$	$\pm 20$	$\pm 20$	
Continuous Drain Current ( $T_J = 150^\circ\text{C}$ )	$T_A = 25^\circ\text{C}$	$I_D$	-0.32	-0.6	-0.6	A
	$T_A = 100^\circ\text{C}$		-0.2	-0.37	-0.37	
Pulsed Drain Current <sup>a</sup>	$I_{DM}$	-2.4	-3	-2	-2	
Power Dissipation	$T_A = 25^\circ\text{C}$	$P_D$	0.8	1.3	2	W
	$T_A = 100^\circ\text{C}$		0.32	0.52	0.8	
Thermal Resistance, Junction-to-Ambient	$R_{thJA}$	156	139	96	62.5	$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150				$^\circ\text{C}$

Notes

a. Pulse width limited by maximum junction temperature.

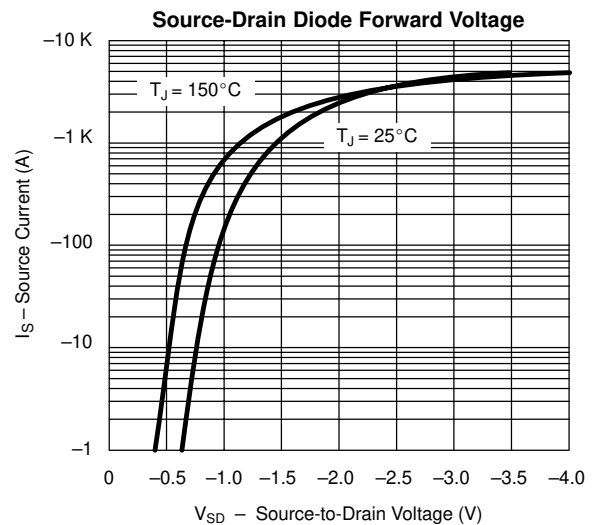
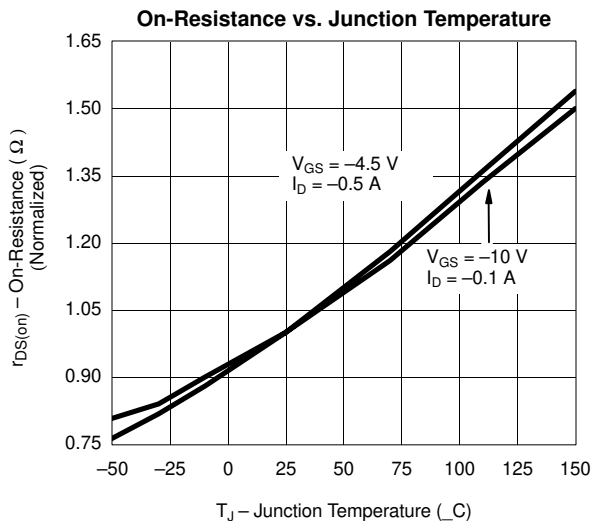
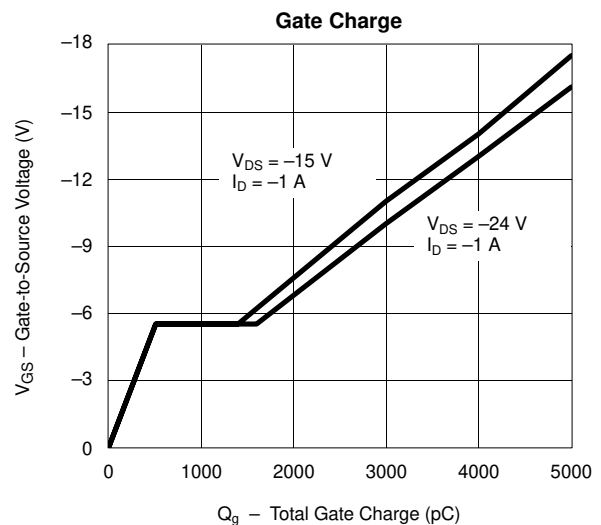
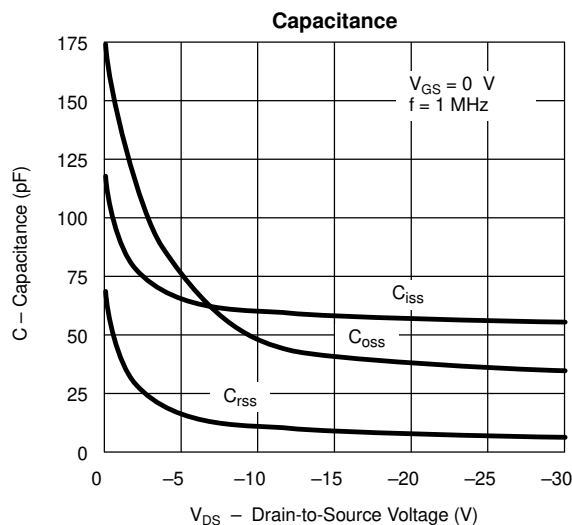
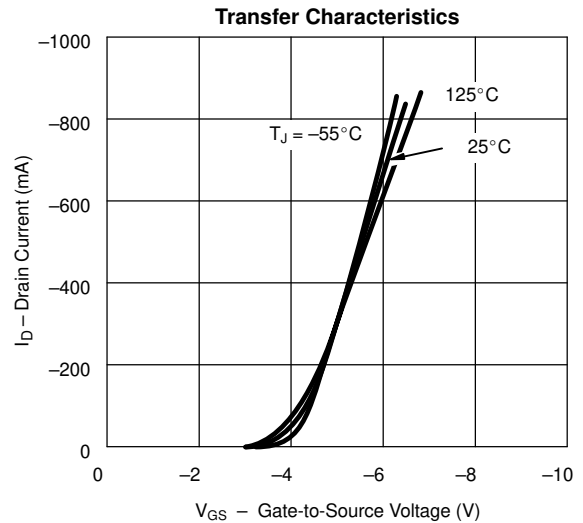
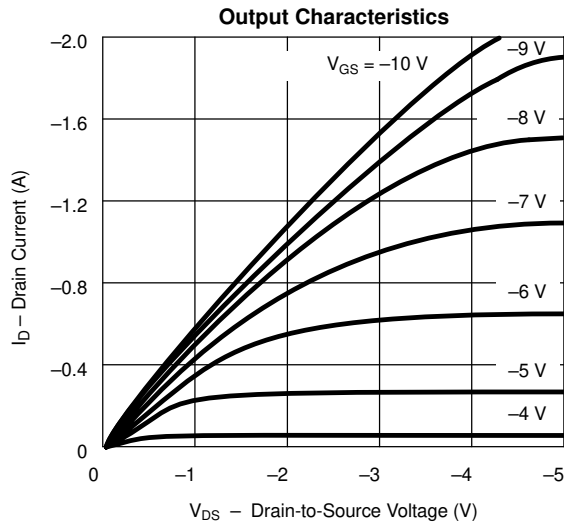
For applications information see AN804.

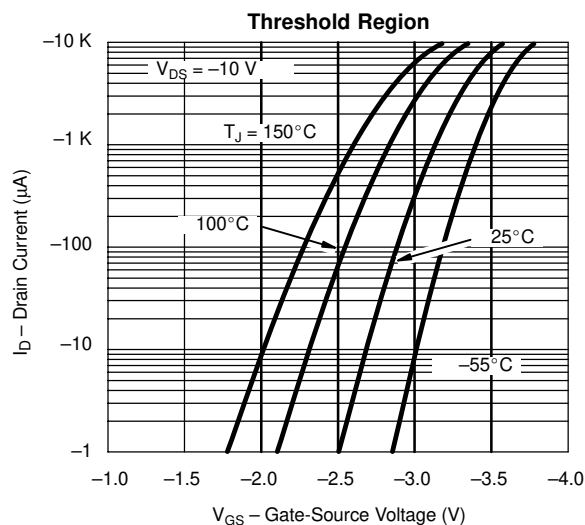
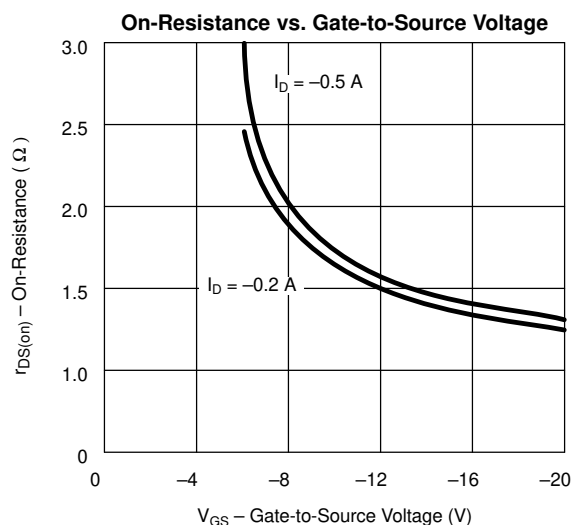
SPECIFICATIONS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)								
Parameter	Symbol	Test Conditions	Typ <sup>a</sup>	Limits				Unit
				VP0300L/LS		VQ2001J/P		
				Min	Max	Min	Max	
Static								
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = −10 μA	−55	−30		−30		V
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = −1 mA	−3.1	−2	−4.5	−2	−4.5	
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 16 V					± 100	nA
		T <sub>J</sub> = 125°C					± 500	
		V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V			± 100			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = −24 V, V <sub>GS</sub> = 0 V			−10			μA
		T <sub>J</sub> = 125°C			−500		−500	
		V <sub>DS</sub> = −30 V, V <sub>GS</sub> = 0 V					−10	
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = −10 V, V <sub>GS</sub> = −12 V	−2.8	−1.5		−1.5		A
Drain-Source On-Resistance <sup>b</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = −12 V, I <sub>D</sub> = −1 A	1.5		2.5		2	Ω
		T <sub>J</sub> = 125°C	2.6		3.6		3.6	
Forward Transconductance <sup>b</sup>	g <sub>fs</sub>	V <sub>DS</sub> = −10 V, I <sub>D</sub> = −0.5 A	370	200		200		mS
Common Source Output Conductance <sup>b</sup>	g <sub>os</sub>	V <sub>DS</sub> = −7.5 V, I <sub>D</sub> = −0.05 A	0.25					
Dynamic								
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = −15 V, V <sub>GS</sub> = 0 V f = 1 MHz	60		150		150	pF
Output Capacitance	C <sub>oss</sub>		40		100		100	
Reverse Transfer Capacitance	C <sub>rss</sub>		10		60		60	
Switching <sup>c</sup>								
Turn-On Time	t <sub>ON</sub>	V <sub>DD</sub> = −25 V, R <sub>L</sub> = 23 Ω I <sub>D</sub> ≅ −1 A, V <sub>GEN</sub> = −10 V R <sub>G</sub> = 25 Ω	19		30			ns
Turn-Off Time	t <sub>OFF</sub>		17		30			
Turn-On Time	t <sub>ON</sub>	V <sub>DD</sub> = −15 V, R <sub>L</sub> = 23 Ω I <sub>D</sub> ≅ −0.6 A, V <sub>GEN</sub> = −10 V R <sub>G</sub> = 25 Ω	19				30	
Turn-Off Time	t <sub>OFF</sub>		16				30	

## Notes

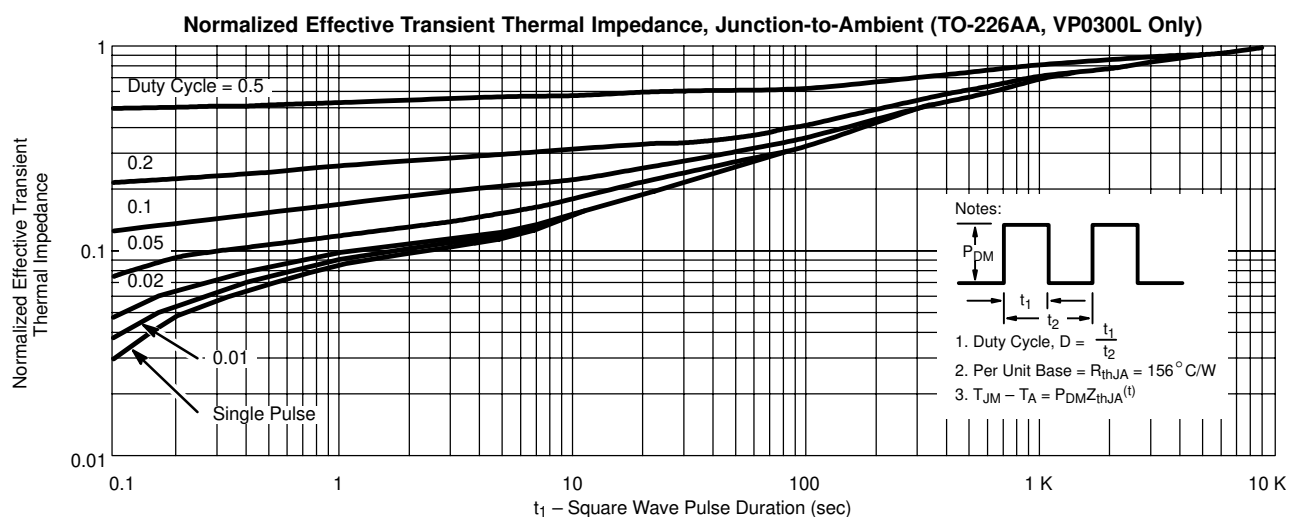
- a. For DESIGN AID ONLY, not subject to production testing.  
b. Pulse test:  $PW \leq 300\text{ }\mu\text{s}$  duty cycle  $\leq 2\%$ .  
c. Switching time is essentially independent of operating temperature.

VPEA03

**TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**

TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)

## THERMAL RATINGS



## DEVICE MARKINGS

## Front View:

VP0300L

"S" VP  
0300L  
xxyy

VP0300LS

"S" VP  
0300LS  
xxyy

## Top View:

VQ2001J

VQ2001J  
"S" f//xxyy

VP0300LS

VQ2001P  
"S" f//xxyy

"S" = Siliconix Logo  
f = Factory Code  
// = Lot Traceability  
xxyy = Date Code



### Disclaimer

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